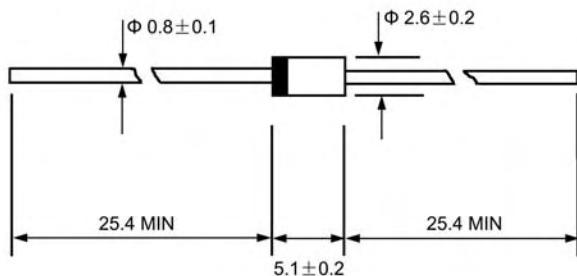


**VOLTAGE RANGE: 70— 600 V**  
**CURRENT: 1.1—0.6 A**
**DO - 41**

## Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropanol and similar solvents



## Mechanical Data

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting: Any

Dimensions in millimeters

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		EG1Y	EG1Z	EG1	EG1A	UNITS
Maximum peak repetitive reverse voltage	$V_{RRM}$	70	200	400	600	V
Maximum RMS voltage	$V_{RMS}$	49	140	280	420	V
Maximum DC blocking voltage	$V_{DC}$	70	200	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	1.1		0.8	0.6	A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	30.0		15.0	10.0	A
Maximum instantaneous forward voltage @ $I_F=I_{F(AV)}$	$V_F$	1.2	1.7	1.8	2.0	V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	$I_R$	100.0 500.0		50.0 300.0	100.0 500.0	$\mu A$
Maximum reverse recovery time (Note1)	$t_{rr}$		50			ns
Typical junction capacitance (Note2)	$C_J$		20	15		pF
Typical thermal resistance (Note3)	$R_{\theta JL}$		60			°C/W
Operating junction temperature range	$T_J$		- 55 ----- + 150			°C
Storage temperature range	$T_{STG}$		- 55 ----- + 150			°C

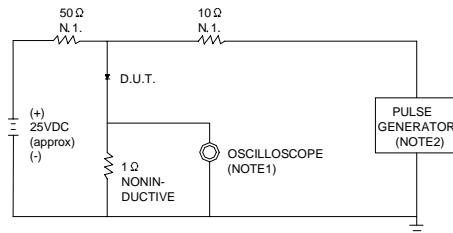
 NOTE: 1. Measured with  $I_F=0.5A$ ,  $I_R=1A$ ,  $I_{rr}=0.25A$ .

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

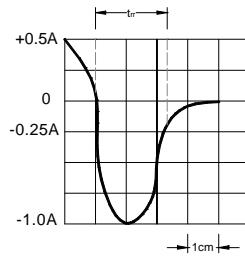
3. Thermal resistance junction to ambient.

## Ratings AND Characteristic Curves

**FIG1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**

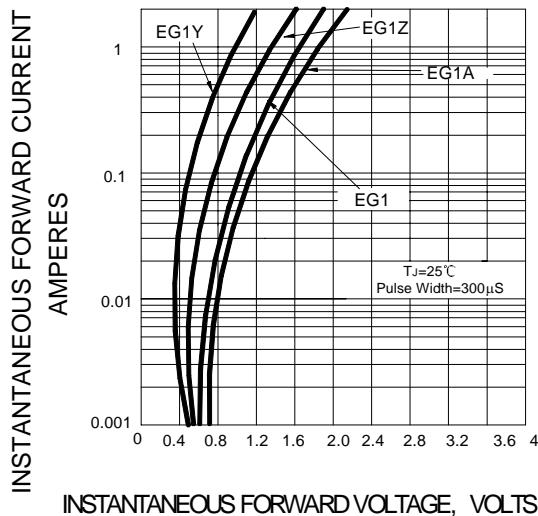


NOTES:  
 1.RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ. 22pF.  
 2.RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.



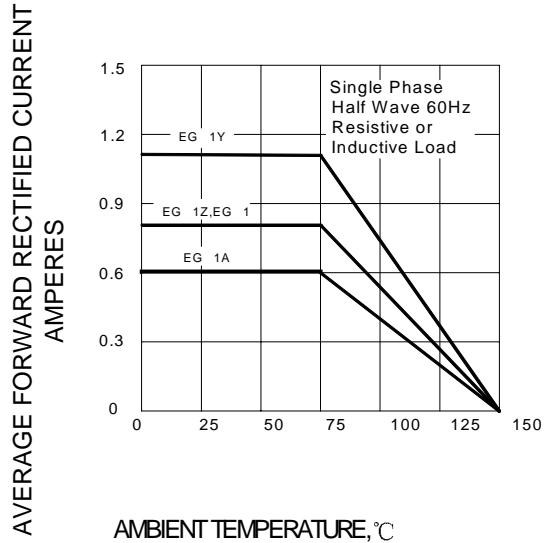
SET TIME BASE FOR 10/20 ns/cm

**FIG2 – TYPICAL FORWARD CHARACTERISTIC**



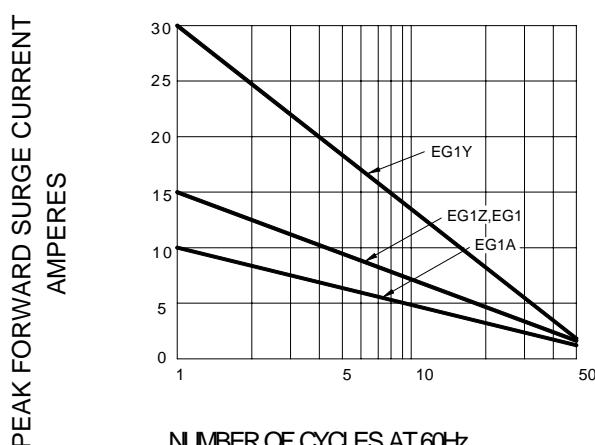
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

**FIG3 – FORWARD DERATING CURVE**



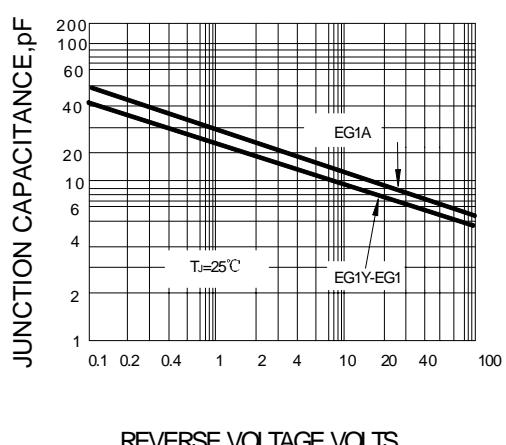
AMBIENT TEMPERATURE, °C

**FIG4 – PEAK FORWARD SURGE CURRENT**



NUMBER OF CYCLES AT 60Hz

**FIG5-TYPICAL JUNCTION CAPACITANCE**



REVERSE VOLTAGE, VOLTS